

CSM212N5.5S23

20V N-Channel Enhancement Mode MOSFET

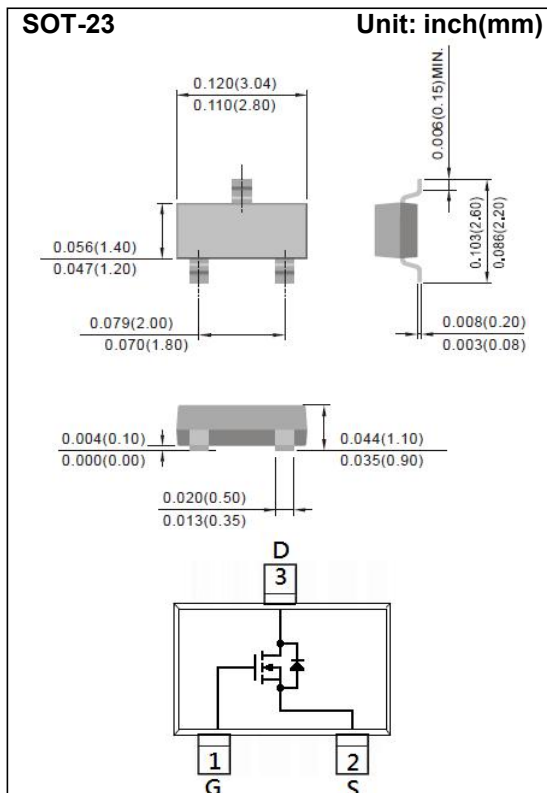
Voltage **20 V** **Current** **5.5A**

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@5.5A < 23m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@3.5A < 30m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	±12	V
Continuous Drain Current		I _D	5.5	A
Pulsed Drain Current		I _{DM}	22	A
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/ °C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance		R _{θJA}	100	°C/W
- Junction to Ambient (Note 3)				

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Electrical Characteristics (T_A=25°C unless otherwise noted)

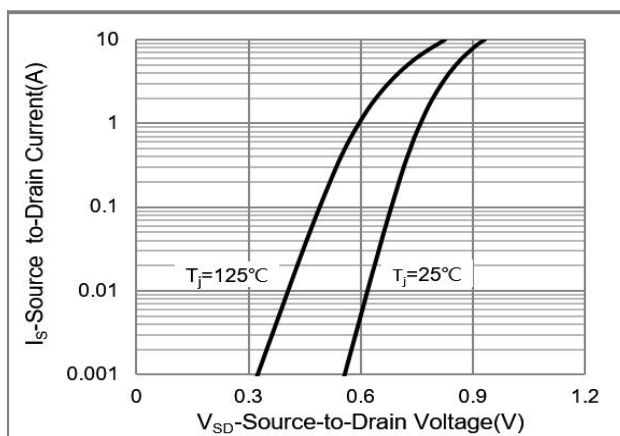
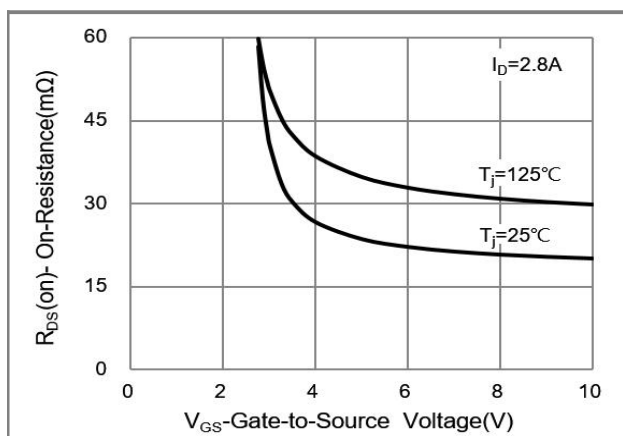
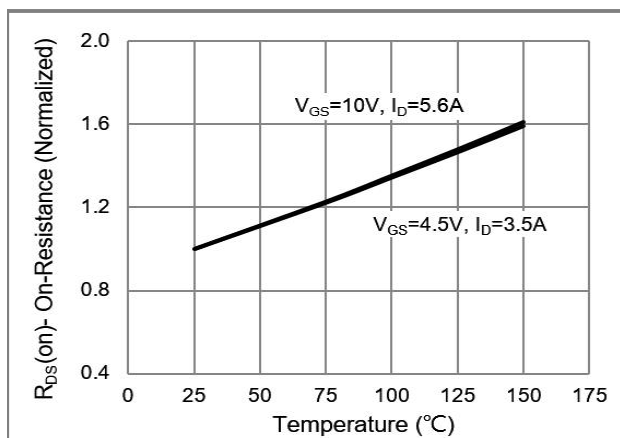
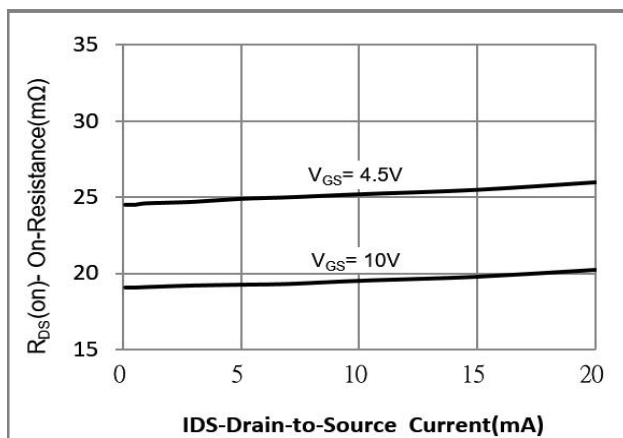
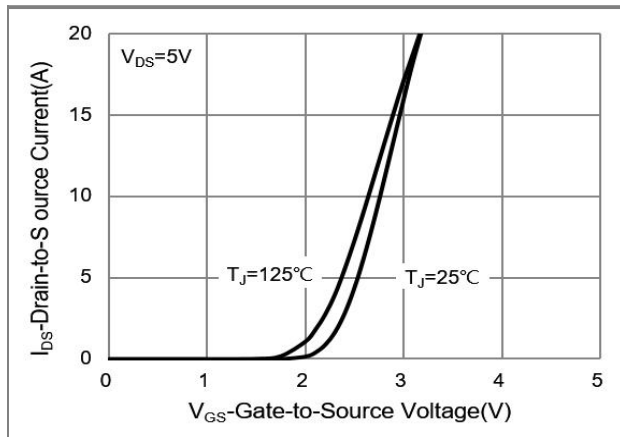
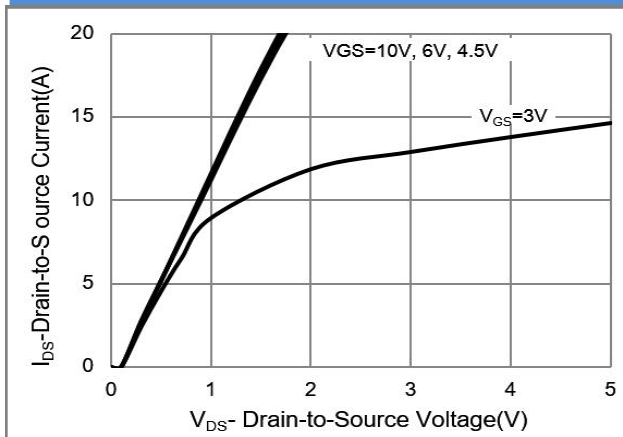
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.57	2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =5.6A	-	20	23	mΩ
		V _{GS} =4.5V, I _D =3.5A	-	24	30	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =15V, I _D =5.6A, V _{GS} =10V (Note 1,2)	-	12.8	-	nC
Gate-Source Charge	Q _{gs}		-	1.6	-	
Gate-Drain Charge	Q _{gd}		-	2.5	-	
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	602	-	pF
Output Capacitance	C _{oss}		-	90	-	
Reverse Transfer Capacitance	C _{rss}		-	67	-	
Turn-On Delay Time	td _(on)	V _{DD} =15V, I _D =5.6A, V _{GS} =10V, R _G =3Ω (Note 1,2)	-	4.7	-	ns
Turn-On Rise Time	tr		-	34	-	
Turn-Off Delay Time	td _(off)		-	15	-	
Turn-Off Fall Time	tf		-	17	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	1.5	A
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.76	1.2	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited
5. Guaranteed by design, not subject to production testing

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TYPICAL CHARACTERISTIC CURVES



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TYPICAL CHARACTERISTIC CURVES

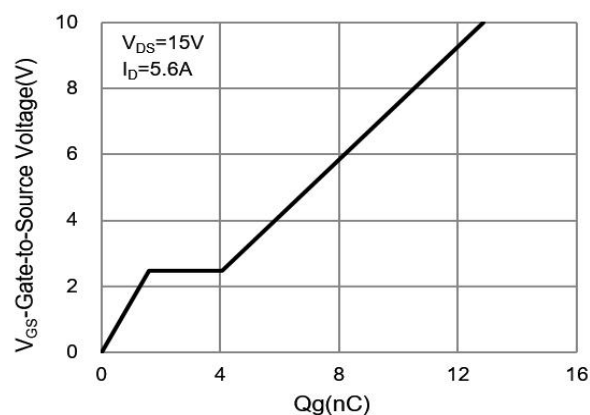


Fig.7 Gate-Charge Characteristics

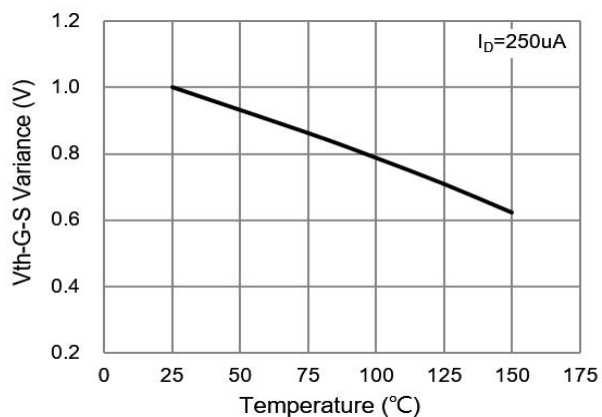


Fig.8 Threshold Voltage Variation with Temperature

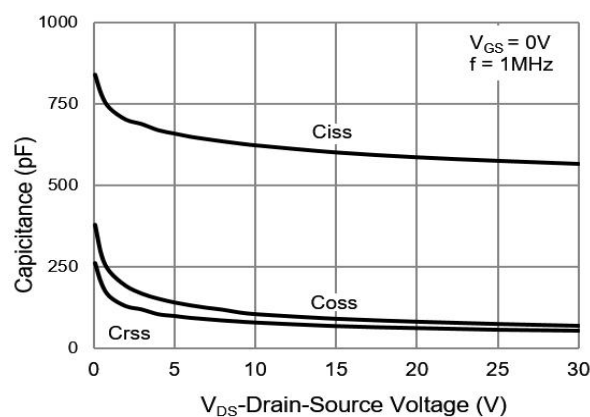


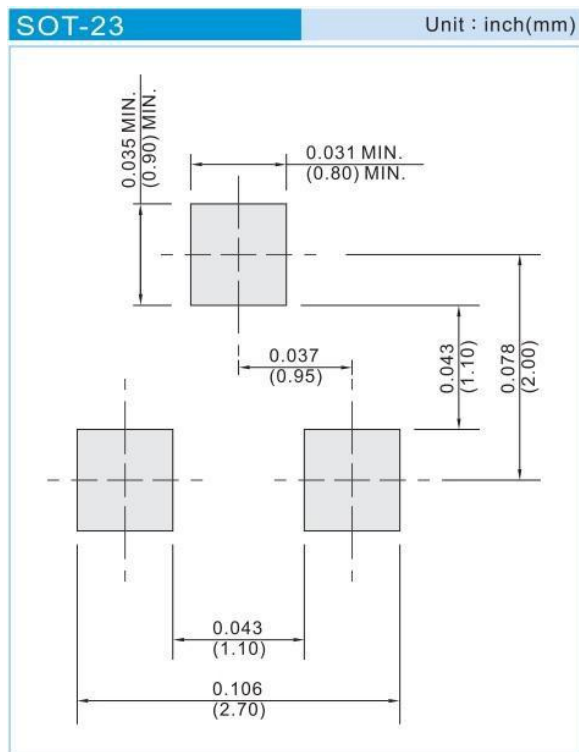
Fig.9 Capacitance vs. Drain-Source Voltage.

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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type
CSM212N5.5S23	SOT-23	3K pcs / 7" reel

MOUNTING PAD LAYOUT



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